OPTICAL AND CHEMICAL PROPERTIES OF MIXED-VALENT RHENIUM OXIDE FILMS SYNTHESIZED BY REACTIVE DC MAGNETRON SPUTTERING (POSTPRINT)

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Functional Materials Division  Functional Materials Division

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### ABSTRACT

Mixed-valent rhenium oxide thin films were deposited using reactive magnetron sputtering employing a metallic rhenium target within an oxygen–argon environment. The oxygen and argon flow rates were systematically varied, while the extinction coefficient, \( k \), of the deposited layers was monitored using in situ spectroscopic ellipsometry. In situ monitoring was used to identify absorption features specific to ReO\(_3\), namely, the minimization of \( k \) brought on by the gap between interband absorption features in the UV at 310 nm and the onset of free electron absorption at wavelengths above 540 nm. Based on these results, oxygen flow ratios of 50% and 60% were shown to produce films having optical properties characteristic of ReO\(_3\), and thus, were selected for detailed ex situ characterization. Chemical analysis via X-ray photoelectron spectroscopy confirmed that all films consisted largely of ReO\(_3\), but had some contributions from Re\(_2\)O\(_3\), ReO\(_2\) and Re\(_2\)O\(_7\). Additional monitoring of the chemistry, as a function of environmental exposure time, indicated a correlation between structural instability and the presence of Re\(_2\)O\(_3\) and Re\(_2\)O\(_7\) in the films.

### SUBJECT TERMS

rhenium oxide, ellipsometry, XPS, thin films, magnetron, sputtering

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Optical and chemical properties of mixed-valent rhenium oxide films synthesized by reactive DC magnetron sputtering

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Abstract

Mixed-valent rhenium oxide thin films were deposited using reactive magnetron sputtering employing a metallic rhenium target within an oxygen–argon environment. The oxygen and argon flow rates were systematically varied, while the extinction coefficient, k, of the deposited layers was monitored using in situ spectroscopic ellipsometry. In situ monitoring was used to identify absorption features specific to ReO3, namely, the minimization of k brought on by the gap between interband absorption features in the UV at 310 nm and the onset of free electron absorption at wavelengths above 540 nm. Based on these results, oxygen flow ratios of 50% and 60% were shown to produce films having optical properties characteristic of ReO3, and thus, were selected for detailed ex situ characterization. Chemical analysis via X-ray photoelectron spectroscopy confirmed that all films consisted largely of ReO3, but had some contributions from Re2O3, ReO2 and Re2O7. Additional monitoring of the chemistry, as a function of environmental exposure time, indicated a correlation between structural instability and the presence of Re2O3 and Re2O7 in the films.

1. Introduction

Rhenium, a hexagonally close packed refractory metal, has several oxides with a variety of interesting optical and electronic properties. The commonly occurring oxides of rhenium are ReO2, ReO3, and Re2O7 [1–7]. The lowest valence oxide, ReO2, is monoclinic in structure, while ReO3 consists of a network of ReO6 octahedra having a cubic, “perovskite-type” structure [4,8]. Finally, Re2O7 consists of ReO6 octahedra and ReO4 tetrahedra, and has been reported to be highly hydroscopic, decomposing into perrhenic acid (HReO4) upon exposure to moisture [1,3,9,10]. The metastable ReO3 is stable under high pressure, decomposing into ReO2 when exposed to moisture [11].

Interestingly, there are no dominant absorption features between 310 and 540 nm (2.3–4 eV), giving rise to a small transmission window within the visible region. Therefore, thin films of ReO3 could also have promise as a transparent-conductive material in applications requiring a narrow transmission band.

Deposition of mixed-valent rhenium oxide thin films has been performed using radio-frequency (RF) magnetron sputtering [9], electrodeposition [5–7,19,20], evaporation from rhenium filaments [1], and reactive direct current magnetron sputtering (DCMS) [4]. At this time, there have been very few studies on the optical and chemical properties of rhenium–oxygen compounds deposited using reactive DCMS [4], which is the subject of this work. Work by Ghanashyam Krishna et al. has described a method of depositing rhenium–oxygen compounds using reactive DCMS, wherein the bias voltage was varied and its effect on the spectral reflectivity was systematically analyzed [4]. Results obtained by Ghanashyam Krishna et al. have shown that the optical and chemical properties of the deposited films can be controlled by varying the bias voltage during deposition.

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Krishna et al. indicate that it is possible to use reactive DCMS to deposit 50–180 nm thin films that demonstrate optical behavior analogous to bulk ReO$_3$, as reported by Weaver et al. [12] and Feinlieb et al. [12]. However, to our knowledge, there are currently no studies reporting on the relationship between the chemistry and spectral (380–1700 nm) optical properties of mixed-valent rhenium oxide thin films deposited via reactive DCMS.

Within this study we devise a method of maximizing the ReO$_3$ content within the films using in situ spectroscopic ellipsometry (ISE). In situ monitoring of the optical behavior, throughout film growth, allows for the selection of oxygen (Q$_{O2}$) and argon (Q$_{Ar}$) flow rates capable of increasing ReO$_3$ content within the films. Process optimization was achieved through real-time identification of characteristic absorption features, namely the minimization of the extinction coefficient, $k$, at wavelengths between 450 and 750 nm (1.65–2.75 eV). After establishing the deposition conditions required for maximizing ReO$_3$ content in the films, analyses of their chemical compositions and their oxidation states, were performed using X-ray photoelectron spectroscopy (XPS). In addition to XPS, X-ray reflectivity (XRR) was used to measure the film thickness and density. These XPS and XRR measurements, as well as additional SE measurements, were made ex situ after one and thirty days exposure to atmosphere at ambient temperatures of 20–25 °C and relative humidity between 20% and 25%. Based on the aforementioned reports of instability [1,3,9,10], it is important to analyze environmental robustness prior to using ReO$_3$ thin films for applications requiring consistent optical performance and structural stability.

2. Materials and methods

2.1. Deposition

Rhenium oxide thin films were deposited within a stainless steel high vacuum chamber evacuated to a pressure of $5.3 \times 10^{-5}$ Pa ($4 \times 10^{-7}$ Torr). A 3 mm thick, 50 mm diameter rhenium sputter target (99.99%, K.J. Lesker), was magnetically attached to a 50 mm magnetron source (MeiVac, MAK) at an angle of 20° with respect to the substrate normal. The distance between the target and the p-type silicon (100) (University Wafer LLC) substrate was 9 cm. During deposition, research grade O$_2$ (99.995%) and Ar (99.999%) were introduced via separate mass flow controllers, mixed prior to entering the chamber, and maintained at a total pressure of 1.33 Pa (10 mTorr) at a pumping speed of 25 L/s [21]. Oxygen and argon content were regulated by controlling the flow rates Q$_{O2}$ and Q$_{Ar}$, while the total flow rate Q$_{TOT}$ was kept constant at 20 sccm. The oxygen fraction f$_{O2}$, represented by Q$_{O2}$/Q$_{TOT}$, was varied from f$_{O2} = 0.0$–0.8 by increments of 0.1, while the optical constants were monitored every ten seconds using in situ spectroscopic ellipsometry. In situ data were gathered during continuous deposition for a period of one minute at each increment of f$_{O2}$. Values of f$_{O2}$ resulting in film layers with minimal extinction coefficients throughout the visible region (400 < $\lambda$ < 750 nm) were selected and used in the deposition of multiple films for further ex situ analysis. The films selected for ex situ optical and chemical analysis were deposited for three minutes at a cathode voltage $V_c$ = 631 V and current $I_c$ = 80 mA, resulting in an applied power of 50 W. Depositions took place upon a substrate platen set to rotate at 12 RPM to mitigate the anisotropy imparted by the sputtering process. Note that no heating, outside of thermal contributions from the plasma, was applied to the substrate.

2.2. Characterization

The optical constants of the rhenium oxide films were measured using a J.A. Woollam M2000VI spectroscopic ellipsometer (SE) at an angle of incidence of 70°, near the Brewster’s angle for silicon. The extinction coefficient ($k$) and the refractive index ($n$) were obtained upon fitting the raw polarization data to the Kramer’s Kronig consistent model described within Section 3.4. Thickness values obtained through spectroscopic ellipsometry were verified using a KLA-Tencor stylus profilometer.

XPS was performed using a Physical Electronics 5700 equipped with an Al Kx X-ray source operating at 1486.6 eV. The energy scale was calibrated using Au and Cu, according to the procedures outlined by the ISO Standard, ISO 15472. Survey scans were acquired at an analyzer pass energy of 187.85 eV (0.80 eV energy step) while high energy resolution scans of the core level Re 4f, Re 4s, C 1s, and O 1s transitions were acquired at a pass energy of 29.35 eV (0.125 eV energy step). High energy resolution spectra were calibrated with respect to the Re 4f$_{7/2}$ transition, corresponding to the Re$^{4+}$ valence state, at a binding energy of 44.9 (±0.1) eV, as reported by Tysoe et al. [1]. This reference energy was used for all films in order to allow for any small electrical charging. To mitigate the level of error present in peak fittings, the spacing between the 4f$_{5/2}$ and 4f$_{7/2}$ components was constrained to reflect spin-orbit splitting of 2.5 eV [22]. Additionally, the components of the 4f doublets were fit using equal full-width-half-maximum values, as well as area ratios of 3:4 (4f$_{5/2}$:4f$_{7/2}$) [19]. Shirley background subtraction and 70% Gaussian 30% Lorentzian line shapes were used to fit all spectra within the CasaXPS 2.3.16 software package [23]. To obtain a metallic reference for use in quantifying binding energy shifts, some samples were sputtered for 5 min using a differentially pumped ion gun at 4 keV with an argon pressure of $10 \times 10^{-3}$ Pa and an emission current of 25 mA. The binding energy obtained for the metallic Re$^{0}$ 4f$_{7/2}$ peak was 40.3 eV. Note that no sputtering was utilized prior to analysis of survey and high resolution scans due to the facile reduction of higher order rhenium–oxygen compounds during sputtering [24,25].

Electron micrographs were taken using an FEI Sirion scanning electron microscope (SEM). Measurements of the films’ densities were performed via X-ray reflectivity analysis (XRR) using a Rigaku Smartlab X-ray diffractometer, while grazing incidence X-ray diffraction (GIXRD) was also performed, indicating that all films deposited were amorphous. The observation of the films’ amorphous character is in line with results obtained by Hahn et al. for cathodically electrodeposited ReO$_3$ thin films [6]. In the absence of crystalline character related to various rhenium–oxygen coordination compounds, establishment of the presence of individual compounds was performed through careful analysis of relative charge shifts present within high energy resolution XPS spectra. Further corroboration of the presence of specific compounds, namely ReO$_3$, was performed through comparison of SE data with data presented within the literature.

3. Results and discussion

3.1. In situ monitoring of optical constants

In situ ellipsometry measurement of rhenium oxide as a function of increasing oxygen content was used in order to determine the oxygen fraction required to minimize the $k$ within the visible region (400 < $\lambda$ < 750 nm). Since oxides of rhenium are not dielectric, like many transition metal oxides, the onset of arcing and process instability as a function of increasing f$_{O2}$ was not an issue. As shown in Fig. 1, values of $k$ at 450, 600 and 750 nm, are consistent with reported values for metallic rhenium at f$_{O2}$ ~ 0.0 [26]. As f$_{O2}$ is increased, $k$ values continue to decrease until reaching f$_{O2}$ = 0.4, where a slight increase in $k$ occurs as the potential result of the onset of absorption features related to lower valent rhenium species [20]. As f$_{O2}$ increases, to 0.5 and 0.6, the target surface begins...
to become increasingly coated with adsorbed oxygen, corresponding to a deposition environment conducive to the growth of ReO$_3$, as evinced by the characteristic reduction in $k$ between 450 and 750 nm [4,12,13]. Further increases in $f_{O_2}$ to 0.7 and above, lead to larger values of $k$. The observed increases in $k$ at $f_{O_2} > 0.6$ are likely due to the formation of Re$_2$O$_7$, however, further work would be necessary to quantify the optical behavior of Re$_2$O$_7$ within this region. For depositions taking place at $f_{O_2} < 0.6$, the $k$ minima occur near 450 nm, with the lowest values, 0.2 and 0.6, corresponding to $f_{O_2} = 0.6$ and 0.5, respectively. Diffuse reflectance studies of bulk, single crystal ReO$_3$ performed by Weaver et al. [13] and Feinleib et al. [12] reported values of $k_{450 \text{ nm}} = 0.0$ and 0.2, respectively. Despite differences in morphology and crystallinity, good agreement exists between the in situ optical constants obtained at $f_{O_2} = 0.6$ and reported values [12,13]. Therefore, rhenium oxide thin films were subsequently deposited at $f_{O_2} = 0.5$ and 0.6 and characterized extensively using SEM, XRR, XPS and SE, as discussed below.

### 3.2. Microstructural characterization

Secondary electron micrographs of rhenium oxide films deposited at $f_{O_2} = 0.5$ and $f_{O_2} = 0.6$ are shown in Fig. 2 after 30 days air exposure. The microstructure of the film deposited at $f_{O_2} = 0.5$ shows a dendritic structure dotted with dark features that appear to be in the form of droplets (Fig. 1a, inset). Rhenium oxide deposited at $f_{O_2} = 0.6$ (Fig. 1b) is shown to contain a large, interconnected network of cracks. These cracks appear to be a consequence of buckling induced by compressive stress as a result of the volumetric expansion of the film (Fig. 2a, inset). Expansion and droplet formation are thought to be the result of the instability of Re$_2$O$_7$ ($\rho = 6.10 \text{ g/cm}^3$), forming HReO$_4$ ($\rho = 2.15 \text{ g/cm}^3$) upon exposure to moisture [3,27]. The films’ non-uniform microstructure and poor adhesion are similar to reports of instability associated with the presence of Re$_2$O$_7$ and perhenic acid, HReO$_4$ [1,3,6,8,9,27].

XRR, described in detail by Ferrari et al. [28], was utilized to calculate the density of the rhenium oxide films after 1 day and 30 days of atmospheric exposure. Due to the high levels of macro-segregation, and the resulting non-uniform surface morphology, XRR analysis was limited to the calculation of density by measurement of the total reflection, or critical angle [28]. Films deposited at $f_{O_2} = 0.6$ were shown to retain their initial density of 5.2 g/cm$^3$, while films deposited at $f_{O_2} = 0.5$ showed an average density reduction from 5.0 to 3.8 g/cm$^3$. Typical densities for rhenium oxides range from 11.4 g/cm$^3$ for ReO$_2$ to 6.10 g/cm$^3$ for Re$_2$O$_7$ [3,27]. Density values far below the relatively low density of Re$_2$O$_7$ are indicative of the presence of much lower density HReO$_4$. Thickness measurements via SE for $f_{O_2} = 0.5$ show a thickness increase from 80 (±10) nm in vacuo to 150 (±20) nm, after 30 days air exposure. Films deposited at $f_{O_2} = 0.6$ were 90 (±7) nm thick in vacuo and 93 (±7) nm after 30 days air exposure, essentially unchanged. Despite microstructural non-uniformity, thickness changes for $f_{O_2} = 0.5$ measured by ellipsometry correlate to volumetric expansion related to their density reduction after 30 days.

### 3.3. Surface analysis

The compositions and chemical states of the rhenium oxide films, measured using XPS, demonstrated marked changes as a result of environmental exposure. Survey (Fig. 3) and high-resolution (Fig. 4) scans were acquired for films deposited at $f_{O_2} = 0.5$ and 0.6 after exposure to air for 1 and 30 days. The initial survey scan of the film deposited at $f_{O_2} = 0.5$ after 1 day of exposure showed a composition of 30% Re, and perhenic acid, HReO$_4$ [1,3,6,8,9,27].

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at $f_{O_2} = 0.6$, following air exposures of 1 and 30 days changed from 30% to 27% Re, 70% to 65% O, and 0% to 8% C, respectively. Note that the atomic compositions were similar after 1 day air exposure, but as discussed below, their rhenium oxidation states are very different.

High resolution XPS (Fig. 4), performed after 1 day of air exposure, indicated that all films deposited were found to contain 4f transitions with binding energies corresponding valence states of Re$^{4+}$, Re$^{6+}$, Re$^{7+}$, for their respective compounds: ReO$_2$, ReO$_3$, and Re$_2$O$_7$ [1,18,29]. In addition to these compounds, films deposited at $f_{O_2} = 0.5$ were found to contain up to 15% of the Re$^{3+}$ valence state. The presence of the Re$^{3+}$ valence state, and its corresponding oxide, Re$_2$O$_3$, has been reported previously in the literature [6,25,30,31]. Interestingly, Re$_2$O$_3$ has been reported to undergo catalytic disproportionation in the presence of moisture, decomposing into metallic Re$^0$ and hydrous ReO$_2$, as described in Eq. (1) [6,30,31]:

$$2\text{Re}_2\text{O}_3 + 6\text{H}_2\text{O} \rightarrow \text{Re}^0 + 3(\text{ReO}_2 \cdot \text{H}_2\text{O})$$

Binding energies corresponding to the Re 4f$_{7/2}$ transitions are shown within Table 1. The chemical state distribution measured for $f_{O_2} = 0.5$ (Fig. 4a) after 1 day air exposure consists of 15% Re$^{3+}$, 10% Re$^{4+}$, 55% Re$^{6+}$, and 20% Re$^{7+}$. After air exposure for $t = 30$ days (Fig. 4a), the surface chemistry is 7% Re$^{3+}$, 5% Re$^{4+}$, 88% Re$^{6+}$, and 0% Re$^{7+}$. Given the reported instability of both Re$_2$O$_3$ and Re$_2$O$_7$ in the presence of moisture [1,3,6,8,9,27], it is possible that both hydrous ReO$_2$ and liquid HReO$_4$ could have formed during environmental exposure and subsequently vaporized under the UHV conditions within the XPS instrument. Tysoe, et al., have reported similar losses of rhenium species, correlated to the presence of Re$_2$O$_7$ [1]. Films deposited at $f_{O_2} = 0.6$ (Fig. 4b) were found to contain 40% Re$^{4+}$, 53% Re$^{6+}$, and 7% Re$^{7+}$ after 1 day, and 40% Re$^{4+}$, 50% Re$^{6+}$, and 10% Re$^{7+}$ after 30 days, exhibiting very little change as a result of environmental exposure. Therefore, according to the XPS results, the surface chemistry of films grown at $f_{O_2} = 0.6$

![Fig. 3. XPS survey scans used for composition measurement for films deposited at $f_{O_2} = 0.5$ and 0.6 after 1 day air exposure.](image)

![Fig. 4. High resolution XPS spectra of the Re 4f transitions after 1 and 30 days air exposure for films deposited at (a) $f_{O_2} = 0.5$ and (b) 0.6. Spectra are offset for clarity.](image)

![Fig. 5. Plot of the binding energy shift for the Re 4f$_{7/2}$ peak as a function of oxidation state, as compared to results obtained by Liu et al. [32], Cimino et al. [29], Tysoe et al. [1], Shpiro et al. [35], and Komiyama et al. [25].](image)

<table>
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<th>Oxidation state</th>
<th>$f_{O_2} = 0.5$ binding energy (eV)</th>
<th>$f_{O_2} = 0.6$ binding energy (eV)</th>
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<td>6+</td>
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<tr>
<td>7+</td>
<td>46.4</td>
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Table 1

Re 4f$_{7/2}$ binding energies measured from curve fitted data for $f_{O_2} = 0.5$ and 0.6.
remained relatively stable, while films grown at \( f_{O_2} = 0.5 \) demonstrated large changes after 30 days exposure to air.

Given the uncertainty inherent in the peak fitting process, comparisons were made between high energy resolution XPS data obtained for films deposited at \( f_{O_2} = 0.5 \) and 0.6, and those analyzed within the literature [6,25,29,32]. In addition to probing the accuracy of the fitting process, the comparisons shown in Fig. 5 help to identify potential trends in peak location as a function of oxidation state. Identification of known binding energy shifts is especially helpful for the validation of the presence of the unstable Re\(^3+\) oxidation state. Typically, as a result of increases in binding energy brought on by oxygen bonding, the binding energy will increase almost linearly as a function of oxidation number. A similar observed trend for rhenium has been noted elsewhere by Komiyama et al. [25].

The binding energies of the Re 4f\(_{7/2}\) peaks obtained within this study are in good agreement with reported values, as seen in Fig. 5.

### 3.4. Optical properties

Detailed spectroscopic ellipsometry analysis of the rhenium oxide thin films was conducted in vacuo for films grown at \( f_{O_2} = 0.5 \) and 0.6. The measurements were made over a wavelength range of 380–1700 nm. The resulting magnitude (\( \Psi \)) and phase difference (\( \Delta \)) information obtained from the two samples was then parameterized using two Lorentz oscillator models, as described elsewhere by Jellison [33]. Multiple oscillators were required due to the fact that ReO\(_3\) facilitates absorption via interband transitions at \( \lambda < 540 \) nm \((h\nu > 2.3 \text{ eV})\) specifically the tail of the absorption feature centered at 310 nm \((4 \text{ eV})\) as the other interband absorption features are out of the range of ellipsometer used for these measurements. Additional absorption features accounted for within the model include free-electron, or intraband transitions beginning at \( \lambda = 540 \) nm and increasing into the NIR and IR \((h\nu < 2.3 \text{ eV})\) [4,6,12,13]. Oscillator parameters, error estimates, and goodness-of-fit data can be found within Table 2. Fig. 6a shows both the refractive index and extinction coefficient values at different exposure times. For \( f_{O_2} = 0.6 \), initial and prolonged exposure to atmosphere have very little effect on the optical properties. Free electron absorption within the near infrared region is parameterized using a Lorentz oscillator centered at 1940 nm \((0.64 \text{ eV})\) the corresponding extinction coefficients and refractive indices are shown to increase alongside wavelength, as expected in the case of intraband transitions [34]. Interband transitions were measured at 375 nm \((3.3 \text{ eV})\), close to the known ReO\(_3\) absorption band at 310 nm \((4.0 \text{ eV})\); discrepancies between these two values are likely due to the fact that the ellipsometer is currently not equipped to exceed 380 nm \((3.25 \text{ eV})\). Note that ReO\(_3\) undergoes additional interband transitions at 177, 155, 124 and 89 nm \((7, 8, 10 \text{ and } 14 \text{ eV})\) [4,12,13], while Re\(_2\)O\(_7\) has absorption bands at 310 and 240 nm \((4.0 \text{ and } 5.2 \text{ eV})\) [4,10]. Therefore, it will be difficult to determine if absorption occurring at or near 310 nm \((4 \text{ eV})\) is characteristic of either compound. In the case of films deposited at \( f_{O_2} = 0.5 \), the initial optical behavior is similar to the \( f_{O_2} = 0.6 \) films, experiencing interband transitions near 375 nm \((3.3 \text{ eV})\), with intraband absorption occurring above 540 nm \((2.3 \text{ eV})\), centered at 1900 nm \((0.65 \text{ eV})\). Films deposited at \( f_{O_2} = 0.5 \) demonstrate little change upon initial exposure to atmosphere, however, the optical properties are shown to have rapidly degraded after 30 days air exposure. These films no longer demonstrate the characteristic free electron absorption associated with ReO\(_3\), instead they have a very low extinction coefficient, less than 0.7 from

---

### Table 2

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<th>( f_{O_2} )</th>
<th>( t ) (days)</th>
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<th>Center energy (eV)</th>
<th>Thickness (nm)</th>
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<td>0.85 ± 0.01</td>
<td>0.58 ± 0.01</td>
<td>90</td>
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<td></td>
<td>2.8 ± 0.1</td>
<td>0.53 ± 0.01</td>
<td>3.30 ± 0.01</td>
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<tr>
<td></td>
<td>1</td>
<td>28 ± 1</td>
<td>0.91 ± 0.01</td>
<td>0.63 ± 0.01</td>
<td>89</td>
<td>10.3</td>
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<td>30</td>
<td>39 ± 2</td>
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<td>0.64 ± 0.01</td>
<td>93</td>
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<td>1.9 ± 0.1</td>
<td>0.49 ± 0.02</td>
<td>3.27 ± 0.01</td>
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Fig. 6. Optical constants \((n, k)\) obtained for mixed valent rhenium oxide thin films from 380 to 1700 nm, part (a). Note that both refractive index and extinction coefficient values for films deposited at \( f_{O_2} = 0.5 \) in vacuo (thin dashed) and after 1 day exposure (dotted) overlap one another significantly. The 30 day data within the dashed boxes in part (a) are expanded and shown within part (b), along with comparisons to reported values by Feinleib et al. [12], Weaver et al. [13], Ghanashyam Krishna et al. [4] and Hahn et al. [6].

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380 to 1700 nm. In addition, the $f_{O_2} = 0.5$ film required three Lorentz oscillators to accommodate absorption bands at 443, 752 and 295 nm (2.8, 1.65 and 4.2 eV). These films demonstrate similar optical behavior to highly oxidized, solution deposited rhenium oxide compounds obtained by Hahn et al. [6] as shown in Fig. 6b. Additional comparisons between films deposited at $f_{O_2} = 0.6$ and results obtained by Feinleib et al. [12] and Weaver et al. [13], for single crystal ReO$_3$, can be seen in Fig. 6b, where our data indicates reasonably similar optical behavior to their bulk single crystals.

4. Conclusions

Despite having only a 10% difference in $f_{O_2}$ values, rhenium oxide films deposited at $f_{O_2} = 0.5$ and 0.6 have disparate optical and chemical properties, especially as a function of environmental exposure time. While films deposited under both conditions are composed of similar proportions of rhenium to oxygen, 70% O and 30% Re, as calculated via XPS, their chemistries are quite different. The main difference between the oxide species present in films deposited at $f_{O_2} = 0.5$ and 0.6 is the existence of Re$^{3+}$ associated with an oxygen fraction of 0.5. Films containing the Re$^{3+}$ valence state, a result of the lower oxygen fraction used during growth, have demonstrated large decreases in density, droplet formation, poor adhesion, and rapid degradation of optical performance. Similarly, films deposited at $f_{O_2} = 0.6$ have shown poor adhesion, and slight microstructural instability in the form of compressive-mode cracking. However, films deposited at $f_{O_2} = 0.6$ have demonstrated very small changes in their optical and chemical properties as a function of environmental exposure. The poor adhesion and microstructural instability of the mixed valent rhenium oxide films within this study is consistent with other reports of moisture related degradation. Despite the structural implications associated with exposure to moisture, films deposited at an oxygen level sufficient to preclude the formation of Re$^{3+}$ were able to retain their optical and chemical properties throughout the 30 day exposure period.

References